

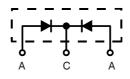
Common Cathode Fast Recovery Epitaxial Diode (FRED)

DSEK 60

 $I_{FAVM} = 2x 34 A$ $V_{RRM} = 200 V$

 $t_{rr} = 35 \text{ ns}$

V _{RSM}	V _{RRM}	Туре
200	200	DSEK 60-02A
200	200	DSEK 60-02AR



TO-247 AD Version A



A = Anode, C = Cathode

Symbol	Test Conditions	Maximum Ratings per leg		
I _{FRMS} *	$T_{VJ} = T_{VJM}$ $T_{C} = 115^{\circ}C$; rectangular, d = 0.5	50 34	A A	
I _{FRM}	t_{p} < 10 μs ; rep. rating, pulse width limited by $T_{_{VJM}}$	375	Α	
I _{FSM}	$T_{v,t} = 45^{\circ}C;$ t = 10 ms (50 Hz), sine	325	Α	
10111	t = 8.3 ms (60 Hz), sine	350	Α	
	$T_{VI} = 150^{\circ}C; t = 10 \text{ ms } (50 \text{ Hz}), \text{ sine}$	290	Α	
	t = 8.3 ms (60 Hz), sine	310	Α	
l²t	$T_{VI} = 45^{\circ}C$ $t = 10 \text{ ms } (50 \text{ Hz}), \text{ sine}$	530	A ² s	
	t = 8.3 ms (60 Hz), sine	510	A ² s	
	$T_{VI} = 150^{\circ}\text{C}; t = 10 \text{ ms } (50 \text{ Hz}), \text{ sine}$	420	A ² s	
	t = 8.3 ms (60 Hz), sine	400	A^2s	
T _{VJ}		-40+150	°C	
T _{VJM}		150	°C	
T _{stg}		-40+150	°C	
P _{tot}	T _c = 25°C	125	W	
M _d *	Mounting torque with screw M3	0.45-0.55/4-5	Nm/lb.in.	
	Mounting torque with screw M3.5	0.45-0.55/4-5	Nm/lb.in.	
V _{ISOL} **	50/60 Hz, RMS, t = 1 minute, leads-to-tab	2500	٧~	
Weight	·	6	g	
* Vorcon A only	*** Version AR only			

^{*} Verson A only; ** Version AR only

Symbol	Test Conditions	Characteris typ.	tic Values po max.	er leg
I _R	$T_{VJ} = 25^{\circ}\text{C}$ $V_{R} = V_{RRM}$ $T_{VJ} = 25^{\circ}\text{C}$ $V_{R} = 0.8 \cdot V_{RRM}$ $T_{VJ} = 125^{\circ}\text{C}$ $V_{R} = 0.8 \cdot V_{RRM}$		200 50μA 5 mA	μА
V _F	$I_F = 30 \text{ A};$ $T_{VJ} = 150^{\circ}\text{C}$ $T_{VJ} = 25^{\circ}\text{C}$		0.85 1.10	V
V_{T0} r_{T} $M\Omega$	For power-loss calculations only $T_{vJ} = T_{vJM}$		0.72 4.2	V
R _{thJC}		0.5	1 K/W	
t _{rr}	$I_F = 1 \text{ A}$; -di/dt = 100 A/ μ s; $V_R = 30 \text{ V}$; $T_{VJ} = 25^{\circ}\text{C}$	35	50ns	
I _{RM}	$V_R = 100 \text{ V}; I_F = 30 \text{ A}; -di_F/dt = 100 \text{ A}/\mu\text{s}$ $-L \le 0.05 \mu\text{H}; T_{VI} = 25^{\circ}\text{C}$	4	5 A	

^{*} I_{FAVM} rating includes reverse blocking losses at $T_{\text{V,JM}}$, $V_{\text{R}} = 0.8 \ V_{\text{RBM}}$, duty cycle d = 0.5 Data according to IEC 60747 refer to a single diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions

Features

- International standard package JEDEC TO-247 AD
- Planar passivated chips
- · Very short recovery time
- · Extremely low switching losses
- Low I_{RM}-values
- Soft recovery behavior
- Epoxy meets UL 94V-0 flammability classification
- Version AR isolated and UL registered E153432

Applications

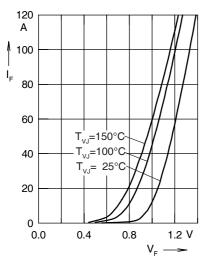
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- · Ultrasonic cleaners and welders

Advantages

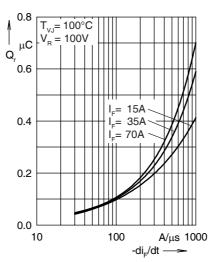
- · High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- · Low losses
- Operating at lower temperature or space saving by reduced cooling



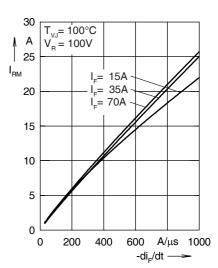




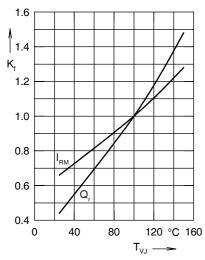
Forward current I_F versus V_F Fig. 1



Typ. reverse recovery charge Fig. 2 Q_{r}



Typ. peak reverse current I_{BM} Fig. 3 versus -di_F/dt



Dynamic parameters Q_r , I_{RM} Fig. 4 versus T_{VJ}

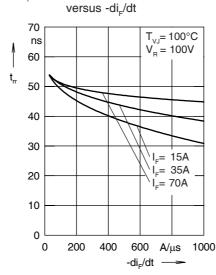


Fig. 5 Typ. recovery time t_{rr} versus -di_/dt

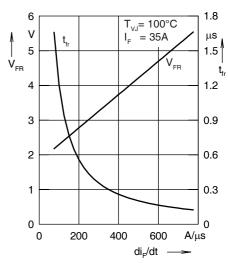
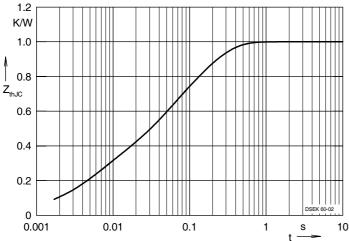
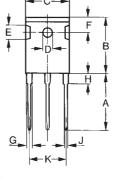


Fig. 6 Typ. peak forward voltage V_{FR} and t_{fr} versus di_F/dt





Dimensions

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G H	1.65	2.13 4.5	0.065	0.084 0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	2.2	2.54	0.087	0.102

Transient thermal impedance junction to case